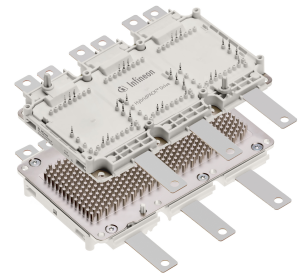


## HybridPACK™ Drive module with CoolSiC™ Automotive MOSFET

### Features

- Electrical features
  - $V_{DS} = 1200\text{ V}$
  - $I_{D,nom} = 400\text{ A}$
  - New semiconductor material - silicon carbide
  - Low  $R_{DS,on}$
  - Low switching losses
  - Low  $Q_g$  and  $C_{rss}$
  - Low inductive design  $<10\text{ nH}$
  - $T_{vj,op} = 150^\circ\text{C}$
- Mechanical features
  - 4.2 kV DC 1 second insulation
  - High creepage and clearance distances
  - Compact design
  - High power density
  - Direct-cooled PinFin base plate
  - High-performance Si3N4 ceramic
  - Guiding elements for PCB and cooler assembly
  - Integrated NTC temperature sensor
  - PressFIT contact technology
  - RoHS compliant
  - UL 94 V0 module frame



### Potential applications

- Automotive applications
- (Hybrid) electrical vehicles (H)EV
- Motor drives
- Commercial agriculture vehicles

### Product validation

- Qualified according to AQG 324, release no.: 03.1/2021

### Description

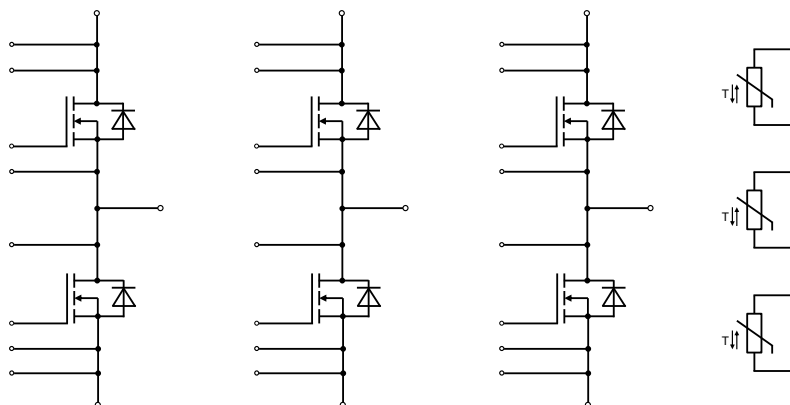


Table of contents

|   |                                |    |
|---|--------------------------------|----|
|   | Description .....              | 1  |
|   | Features .....                 | 1  |
|   | Potential applications .....   | 1  |
|   | Product validation .....       | 1  |
|   | Table of contents .....        | 2  |
| 1 | Package .....                  | 3  |
| 2 | MOSFET .....                   | 4  |
| 3 | Body diode .....               | 5  |
| 4 | NTC-Thermistor .....           | 6  |
| 5 | Characteristics diagrams ..... | 7  |
| 6 | Circuit diagram .....          | 12 |
| 7 | Package outlines .....         | 13 |
| 8 | Module label code .....        | 14 |
|   | Revision history .....         | 15 |
|   | Disclaimer .....               | 16 |

## 1 Package

**Table 1** Insulation coordination

| Parameter                    | Symbol      | Note or test condition                | Values              | Unit |
|------------------------------|-------------|---------------------------------------|---------------------|------|
| Isolation test voltage       | $V_{ISOL}$  | RMS, $f = 0$ Hz, $t = 1$ sec          | 4.20                | kV   |
| Material of module baseplate |             |                                       | Ni+Cu <sup>1)</sup> |      |
| Internal isolation           |             | basic insulation (class 1, IEC 61140) | Si3N4               |      |
| Creepage distance            | $d_{creep}$ | terminal to heatsink                  | 9.0                 | mm   |
| Creepage distance            | $d_{creep}$ | terminal to terminal                  | 9.0                 | mm   |
| Clearance                    | $d_{clear}$ | terminal to heatsink                  | 4.5                 | mm   |
| Clearance                    | $d_{clear}$ | terminal to terminal                  | 4.5                 | mm   |
| Comparative tracking index   | $CTI$       |                                       | > 200               |      |

1) Ni plated Cu baseplate

**Table 2** Maximum rated values

| Parameter                           | Symbol      | Note or test condition                 | Values | Unit |
|-------------------------------------|-------------|----------------------------------------|--------|------|
| Maximum RMS module terminal current | $I_{t,rms}$ | $T_{terminal} = 105$ °C, $T_f = 75$ °C | 500    | A    |

**Table 3** Characteristic values

| Parameter                                | Symbol        | Note or test condition                                                                      | Values |                  |      | Unit |
|------------------------------------------|---------------|---------------------------------------------------------------------------------------------|--------|------------------|------|------|
|                                          |               |                                                                                             | Min.   | Typ.             | Max. |      |
| Pressure drop in cooling circuit         | $\Delta p$    | $\Delta V/\Delta t = 10$ dm <sup>3</sup> /min, 50% water / 50% ethylenglycol, $T_f = 60$ °C |        | 64 <sup>1)</sup> |      | mbar |
| Maximum pressure in cooling circuit      | $p$           | $T_{baseplate} < 40$ °C (relative pressure)                                                 |        |                  | 2.5  | bar  |
|                                          |               | $T_{baseplate} \geq 40$ °C (relative pressure)                                              |        |                  | 2.0  |      |
| Stray inductance module                  | $L_{s,DS}$    |                                                                                             |        | 8.5              |      | nH   |
| Module lead resistance, terminals - chip | $R_{DD'+SS'}$ | $T_f = 25$ °C, per switch                                                                   |        | 0.75             |      | mΩ   |
| Storage temperature                      | $T_{stg}$     |                                                                                             | -40    |                  | 125  | °C   |
| Mounting torque for module mounting      | $M$           | Screw M4 baseplate to heatsink                                                              | 1.8    | 2.0              | 2.2  | Nm   |
| Weight                                   | $G$           |                                                                                             |        | 729              |      | g    |

1) Cooler design and flow direction according to application note AN-HPDPERF-ASSEMBLY

## 2 MOSFET

**Table 4** Maximum rated values

| Parameter            | Symbol        | Note or test condition                            |                              | Values | Unit |
|----------------------|---------------|---------------------------------------------------|------------------------------|--------|------|
| Drain-source voltage | $V_{DS}$      |                                                   | $T_{vj} = 25\text{ °C}$      | 1200   | V    |
| DC drain current     | $I_{D,nom}$   | $V_{GS} = 15\text{ V}$ , $T_f = 60\text{ °C}$     | $T_{vj,max} = 175\text{ °C}$ | 400    | A    |
| Pulsed drain current | $I_{D,pulse}$ | verified by design, $t_p$ limited by $T_{vj,max}$ |                              | 800    | A    |
| Gate-source voltage  | $V_{GSS}$     |                                                   |                              | -10/20 | V    |

**Table 5** Characteristic values

| Parameter                             | Symbol      | Note or test condition                                                                                    |                          | Values |      |      | Unit |
|---------------------------------------|-------------|-----------------------------------------------------------------------------------------------------------|--------------------------|--------|------|------|------|
|                                       |             |                                                                                                           |                          | Min.   | Typ. | Max. |      |
| Drain-source on-resistance            | $R_{DS,on}$ | $I_D = 400\text{ A}$ , $V_{GS} = 15\text{ V}$                                                             | $T_{vj} = 25\text{ °C}$  |        | 2.75 | 3.70 | mΩ   |
|                                       |             |                                                                                                           | $T_{vj} = 125\text{ °C}$ |        | 4.00 |      |      |
|                                       |             |                                                                                                           | $T_{vj} = 150\text{ °C}$ |        | 4.55 |      |      |
| Gate threshold voltage                | $V_{GS,th}$ | $I_D = 240\text{ mA}$ , $V_{GS} = V_{DS}$ ,<br>(tested after 1ms pulse<br>at $V_{GS} = +20\text{ V}$ )    | $T_{vj} = 25\text{ °C}$  | 3.25   | 4.40 | 5.55 | V    |
| Total gate charge                     | $Q_G$       | $V_{DS} = 600\text{ V}$ , $V_{GS} = -5/15\text{ V}$                                                       |                          |        | 1.32 |      | μC   |
| Internal gate resistor                | $R_{G,int}$ |                                                                                                           | $T_{vj} = 25\text{ °C}$  |        | 0.23 |      | Ω    |
| Input capacitance                     | $C_{iss}$   | $f = 1\text{ MHz}$ , $V_{DS} = 600\text{ V}$ ,<br>$V_{GS} = 0\text{ V}$                                   | $T_{vj} = 25\text{ °C}$  |        | 42.6 |      | nF   |
| Output capacitance                    | $C_{oss}$   | $f = 1\text{ MHz}$ , $V_{DS} = 600\text{ V}$ ,<br>$V_{GS} = 0\text{ V}$                                   | $T_{vj} = 25\text{ °C}$  |        | 1.86 |      | nF   |
| Reverse transfer capacitance          | $C_{rss}$   | $f = 1\text{ MHz}$ , $V_{DS} = 600\text{ V}$ ,<br>$V_{GS} = 0\text{ V}$                                   | $T_{vj} = 25\text{ °C}$  |        | 0.17 |      | nF   |
| $C_{oss}$ stored energy               | $E_{oss}$   | $V_{DS} = 600\text{ V}$ , $V_{GS} = -5/15\text{ V}$                                                       | $T_{vj} = 25\text{ °C}$  |        | 438  |      | μJ   |
| Drain-source leakage current          | $I_{DSX}$   | $V_{GS} = -5\text{ V}$ , $V_{DSS} = 1200\text{ V}$                                                        | $T_{vj} = 25\text{ °C}$  |        |      | 100  | μA   |
| Gate-source leakage current           | $I_{GSS}$   | $V_{GS} = 20\text{ V}$ , $V_{DS} = 0\text{ V}$                                                            | $T_{vj} = 25\text{ °C}$  |        |      | 400  | nA   |
| Turn-on delay time,<br>inductive load | $t_{d,on}$  | $I_D = 400\text{ A}$ , $R_{G,on} = 5.1\text{ Ω}$ ,<br>$V_{GS} = -5/15\text{ V}$ , $V_{DS} = 600\text{ V}$ | $T_{vj} = 25\text{ °C}$  |        | 77   |      | ns   |
|                                       |             |                                                                                                           | $T_{vj} = 125\text{ °C}$ |        | 62   |      |      |
|                                       |             |                                                                                                           | $T_{vj} = 150\text{ °C}$ |        | 59   |      |      |
| Rise time (inductive load)            | $t_r$       | $I_D = 400\text{ A}$ , $R_{G,on} = 5.1\text{ Ω}$ ,<br>$V_{GS} = -5/15\text{ V}$ , $V_{DS} = 600\text{ V}$ | $T_{vj} = 25\text{ °C}$  |        | 79   |      | ns   |
|                                       |             |                                                                                                           | $T_{vj} = 125\text{ °C}$ |        | 70   |      |      |
|                                       |             |                                                                                                           | $T_{vj} = 150\text{ °C}$ |        | 69   |      |      |

(table continues...)

**Table 5** (continued) **Characteristic values**

| Parameter                                     | Symbol       | Note or test condition                                                                                                                                   | Values                                                         |       |                     | Unit |
|-----------------------------------------------|--------------|----------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------|-------|---------------------|------|
|                                               |              |                                                                                                                                                          | Min.                                                           | Typ.  | Max.                |      |
| Turn-off delay time, inductive load           | $t_{d,off}$  | $I_D = 400\text{ A}$ , $R_{G,off} = 5.1\ \Omega$ , $V_{GS} = -5/15\text{ V}$ , $V_{DS} = 600\text{ V}$                                                   | $T_{vj} = 25\text{ °C}$                                        | 263   |                     | ns   |
|                                               |              |                                                                                                                                                          | $T_{vj} = 125\text{ °C}$                                       | 287   |                     |      |
|                                               |              |                                                                                                                                                          | $T_{vj} = 150\text{ °C}$                                       | 294   |                     |      |
| Fall time (inductive load)                    | $t_f$        | $I_D = 400\text{ A}$ , $R_{G,off} = 5.1\ \Omega$ , $V_{GS} = -5/15\text{ V}$ , $V_{DS} = 600\text{ V}$                                                   | $T_{vj} = 25\text{ °C}$                                        | 64    |                     | ns   |
|                                               |              |                                                                                                                                                          | $T_{vj} = 125\text{ °C}$                                       | 64    |                     |      |
|                                               |              |                                                                                                                                                          | $T_{vj} = 150\text{ °C}$                                       | 65    |                     |      |
| Turn-on energy loss per pulse                 | $E_{on}$     | $I_D = 400\text{ A}$ , $R_{G,on} = 5.1\ \Omega$ , $V_{GS} = -5/15\text{ V}$ , $V_{DS} = 600\text{ V}$ , $L_\sigma = 20\text{ nH}$                        | $T_{vj} = 25\text{ °C}$ , $di/dt = 4\text{ kA}/\mu\text{s}$    | 19.48 |                     | mJ   |
|                                               |              |                                                                                                                                                          | $T_{vj} = 125\text{ °C}$ , $di/dt = 4.6\text{ kA}/\mu\text{s}$ | 19.85 |                     |      |
|                                               |              |                                                                                                                                                          | $T_{vj} = 150\text{ °C}$ , $di/dt = 4.6\text{ kA}/\mu\text{s}$ | 20.16 |                     |      |
| Turn-off energy loss per pulse                | $E_{off}$    | $I_D = 400\text{ A}$ , $R_{G,off} = 5.1\ \Omega$ , $V_{GS} = -5/15\text{ V}$ , $V_{DS} = 600\text{ V}$ , $L_\sigma = 20\text{ nH}$                       | $T_{vj} = 25\text{ °C}$ , $du/dt = 7.3\text{ kV}/\mu\text{s}$  | 17.61 |                     | mJ   |
|                                               |              |                                                                                                                                                          | $T_{vj} = 125\text{ °C}$ , $du/dt = 7.2\text{ kV}/\mu\text{s}$ | 17.95 |                     |      |
|                                               |              |                                                                                                                                                          | $T_{vj} = 150\text{ °C}$ , $du/dt = 7.1\text{ kV}/\mu\text{s}$ | 18.21 |                     |      |
| Short circuit data                            | $I_{SC}$     | $V_{DD} = 800\text{ V}$ , $V_{GS} = -5/15\text{ V}$ , $R_{G,on} = 5.1\ \Omega$ , $R_{G,off} = 5.1\ \Omega$ , $V_{DSmax} = V_{DSS} - L_{SDS} \cdot di/dt$ | $t_{SC} = 3\ \mu\text{s}$ , $T_{vj} = 25\text{ °C}$            | 5300  |                     | A    |
|                                               |              |                                                                                                                                                          | $t_{SC} = 3\ \mu\text{s}$ , $T_{vj} = 150\text{ °C}$           | 4800  |                     |      |
| Thermal resistance, junction to cooling fluid | $R_{th,j-f}$ | per MOSFET, $T_f = 60\text{ °C}$ , $\Delta V/\Delta t = 10\text{ dm}^3/\text{min}$ , 50% water / 50% ethylenglycol                                       |                                                                | 0.1   | 0.108 <sup>1)</sup> | K/W  |
| Temperature under switching conditions        | $T_{vj,op}$  |                                                                                                                                                          | -40                                                            |       | 150                 | °C   |

1) EoL criteria see AQG324, verified by characterization with 4.5 sigma. Cooler design and flow direction according to application note AN-HPDPERF-ASSEMBLY

### 3 Body diode

**Table 6** **Maximum rated values**

| Parameter                     | Symbol          | Note or test condition                                                       | Values | Unit |
|-------------------------------|-----------------|------------------------------------------------------------------------------|--------|------|
| DC body diode forward current | $I_{F,S}$       | $T_{vj,max} = 175\text{ °C}$ , $T_f = 60\text{ °C}$ , $V_{GS} = -5\text{ V}$ | 210    | A    |
| Pulsed body diode current     | $I_{F,S,pulse}$ | verified by design, $t_p$ limited by $T_{vj,max}$                            | 800    | A    |

**Table 7** Characteristic values

| Parameter                     | Symbol     | Note or test condition                                                              | Values                                                               |       |      | Unit          |
|-------------------------------|------------|-------------------------------------------------------------------------------------|----------------------------------------------------------------------|-------|------|---------------|
|                               |            |                                                                                     | Min.                                                                 | Typ.  | Max. |               |
| Forward voltage               | $V_{F,SD}$ | $I_{F,S} = 400 \text{ A}$ , $V_{GS} = -5 \text{ V}$                                 | $T_{vj} = 25 \text{ °C}$                                             | 4.42  | 6.15 | V             |
|                               |            |                                                                                     | $T_{vj} = 125 \text{ °C}$                                            | 4.22  |      |               |
|                               |            |                                                                                     | $T_{vj} = 150 \text{ °C}$                                            | 4.16  |      |               |
| Peak reverse recovery current | $I_{rrm}$  | $I_{F,S} = 400 \text{ A}$ , $V_{GS} = -5 \text{ V}$ ,<br>$V_{R,DS} = 600 \text{ V}$ | $T_{vj} = 25 \text{ °C}$                                             | 165   |      | A             |
|                               |            |                                                                                     | $T_{vj} = 125 \text{ °C}$                                            | 287   |      |               |
|                               |            |                                                                                     | $T_{vj} = 150 \text{ °C}$                                            | 309   |      |               |
| Recovered charge              | $Q_{rr}$   | $I_{F,S} = 400 \text{ A}$ , $V_{GS} = -5 \text{ V}$ ,<br>$V_{R,DS} = 600 \text{ V}$ | $T_{vj} = 25 \text{ °C}$                                             | 11.20 |      | $\mu\text{C}$ |
|                               |            |                                                                                     | $T_{vj} = 125 \text{ °C}$                                            | 18.10 |      |               |
|                               |            |                                                                                     | $T_{vj} = 150 \text{ °C}$                                            | 19.30 |      |               |
| Reverse recovery energy       | $E_{rec}$  | $I_{F,S} = 400 \text{ A}$ , $V_{GS} = -5 \text{ V}$ ,<br>$V_{R,DS} = 600 \text{ V}$ | $T_{vj} = 25 \text{ °C}$ ,<br>$-di/dt = 5.9 \text{ kA}/\mu\text{s}$  | 1.4   |      | mJ            |
|                               |            |                                                                                     | $T_{vj} = 125 \text{ °C}$ ,<br>$-di/dt = 6.9 \text{ kA}/\mu\text{s}$ | 4.0   |      |               |
|                               |            |                                                                                     | $T_{vj} = 150 \text{ °C}$ ,<br>$-di/dt = 6.9 \text{ kA}/\mu\text{s}$ | 4.7   |      |               |

## 4 NTC-Thermistor

**Table 8** Characteristic values

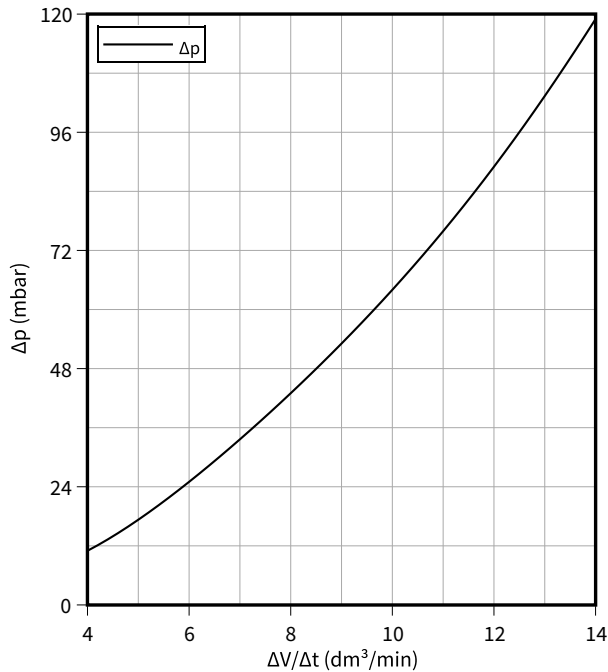
| Parameter              | Symbol       | Note or test condition                                        | Values |      |      | Unit       |
|------------------------|--------------|---------------------------------------------------------------|--------|------|------|------------|
|                        |              |                                                               | Min.   | Typ. | Max. |            |
| Rated resistance       | $R_{25}$     | $T_{NTC} = 25 \text{ °C}$                                     |        | 5    |      | k $\Omega$ |
| Deviation of $R_{100}$ | $\Delta R/R$ | $T_{NTC} = 100 \text{ °C}$ , $R_{100} = 493 \text{ }\Omega$   | -5     |      | 5    | %          |
| Power dissipation      | $P_{25}$     | $T_{NTC} = 25 \text{ °C}$                                     |        |      | 20   | mW         |
| B-value                | $B_{25/50}$  | $R_2 = R_{25} \exp[B_{25/50}(1/T_2 - 1/(298,15 \text{ K}))]$  |        | 3375 |      | K          |
| B-value                | $B_{25/80}$  | $R_2 = R_{25} \exp[B_{25/80}(1/T_2 - 1/(298,15 \text{ K}))]$  |        | 3411 |      | K          |
| B-value                | $B_{25/100}$ | $R_2 = R_{25} \exp[B_{25/100}(1/T_2 - 1/(298,15 \text{ K}))]$ |        | 3433 |      | K          |

5 Characteristics diagrams

Pressure drop in cooling circuit, Package

$\Delta p = f(\Delta V/\Delta t)$

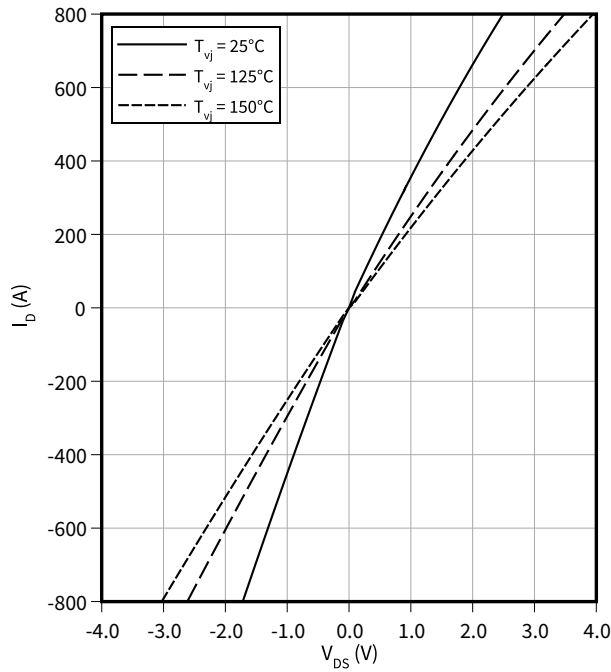
$T_f = 60\text{ }^{\circ}\text{C}$ , fluid = 50% water/50% ethylenglycol



Output characteristic (typical), MOSFET

$I_D = f(V_{DS})$

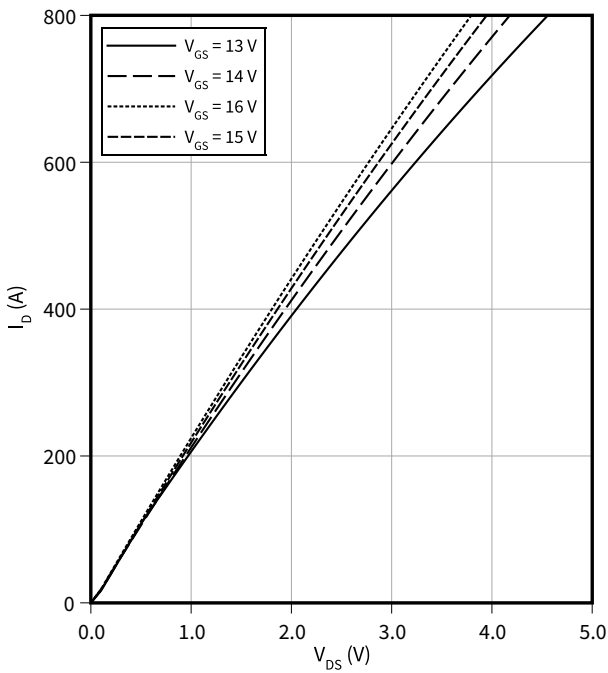
$V_{GS} = 15\text{ V}$



Output characteristic (typical), MOSFET

$I_D = f(V_{DS})$

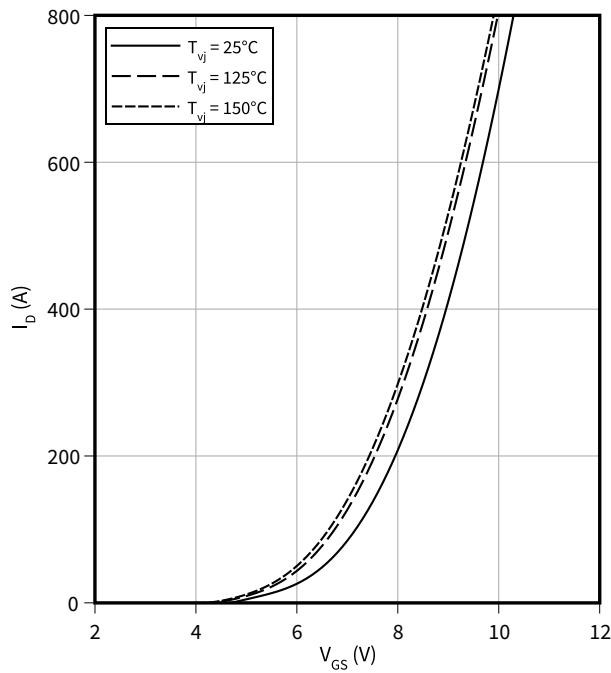
$T_{vj} = 125\text{ }^{\circ}\text{C}$



Transfer characteristic (typical), MOSFET

$I_D = f(V_{GS})$

$V_{DS} = 20\text{ V}$

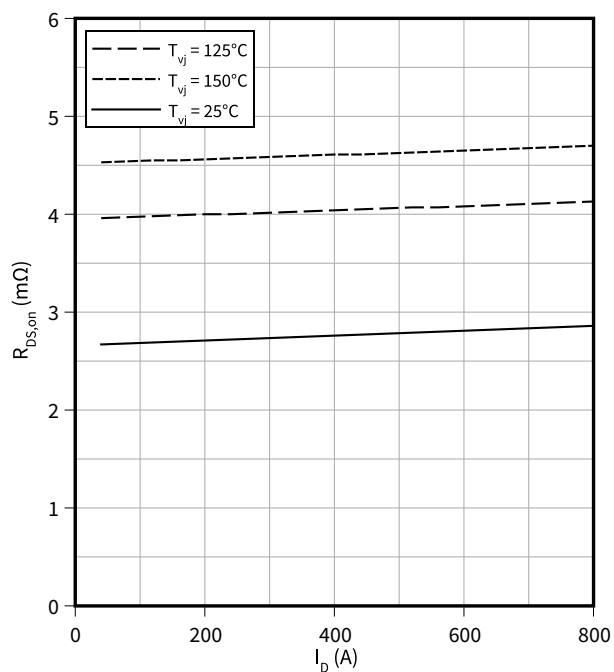


5 Characteristics diagrams

**Drain-source on-resistance (typical), MOSFET**

$$R_{DS,on} = f(I_D)$$

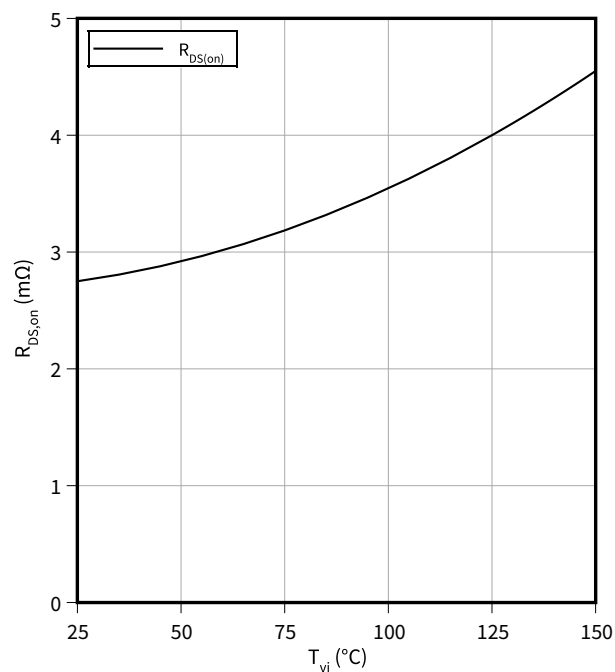
$$V_{GS} = 15 \text{ V}$$



**Drain-source on-resistance (typical), MOSFET**

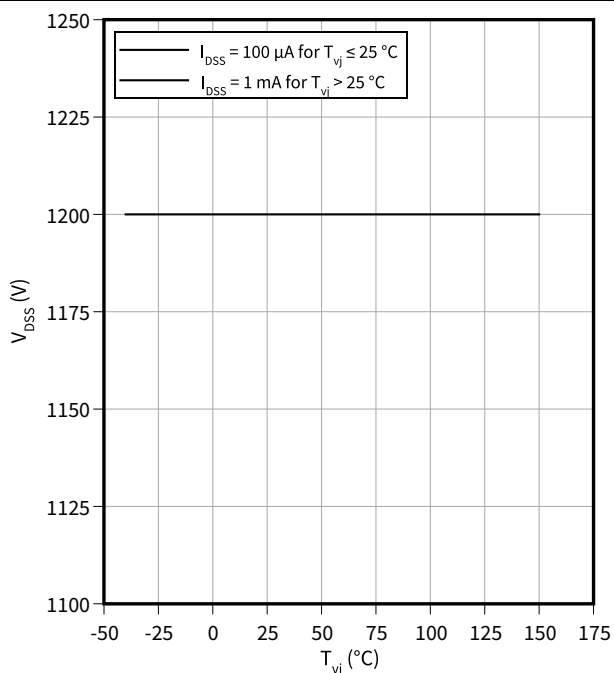
$$R_{DS,on} = f(T_{vj})$$

$$I_D = 400 \text{ A}, V_{GS} = 15 \text{ V}$$



**Maximum allowed drain-source voltage, MOSFET**

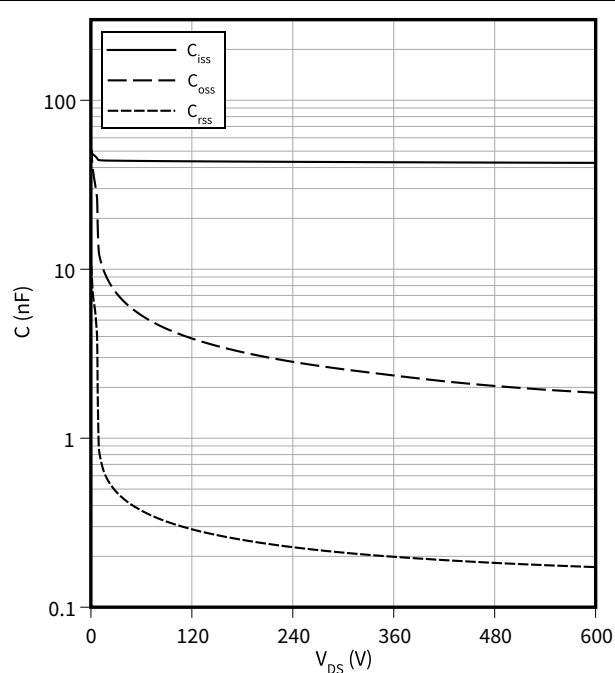
$$V_{DSS} = f(T_{vj})$$



**Capacity characteristic (typical), MOSFET**

$$C = f(V_{DS})$$

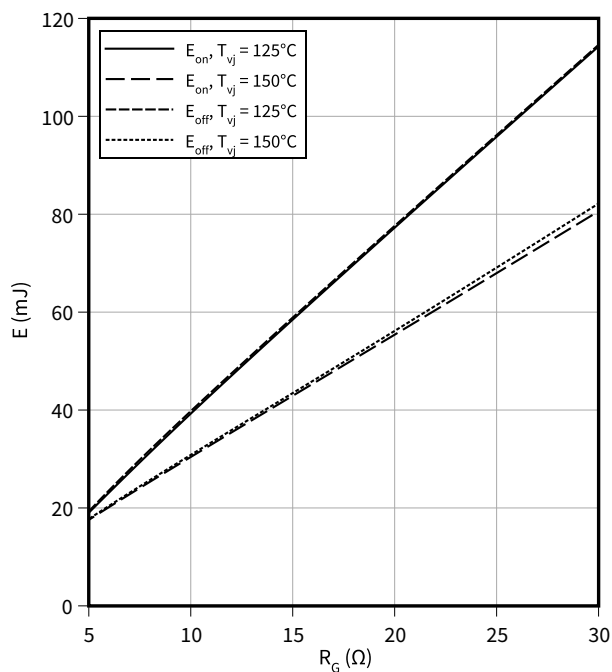
$$T_{vj} = 25^\circ\text{C}, f = 1 \text{ MHz}, V_{GS} = 0 \text{ V}$$



**Switching losses (typical), MOSFET**

$$E = f(R_G)$$

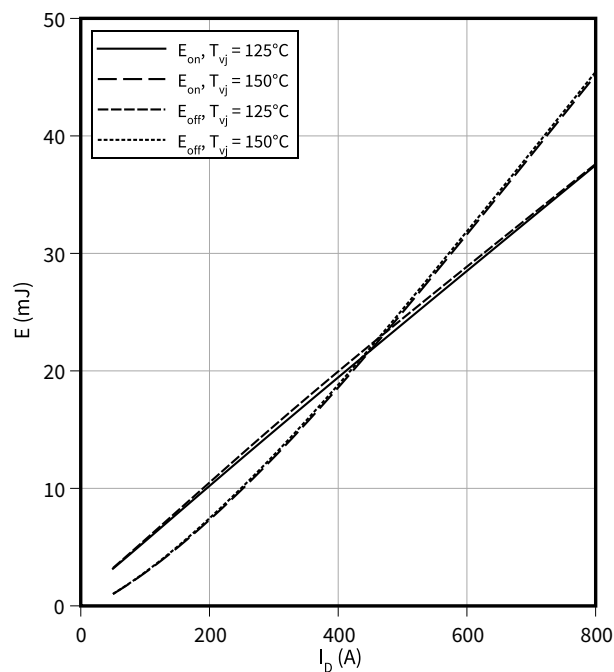
$I_D = 400 \text{ A}$ ,  $V_{DS} = 600 \text{ V}$ ,  $V_{GS} = -5/15 \text{ V}$



**Switching losses (typical), MOSFET**

$$E = f(I_D)$$

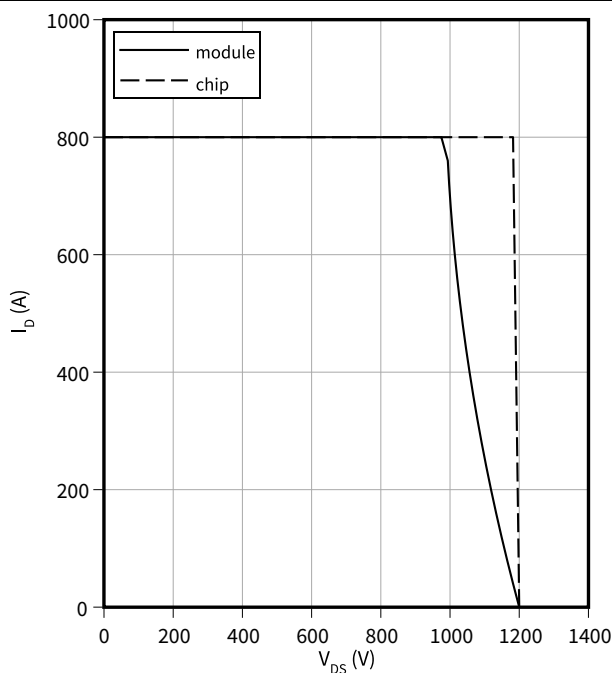
$V_{DS} = 600 \text{ V}$ ,  $R_{G,off} = 5.1 \Omega$ ,  $R_{G,on} = 5.1 \Omega$ ,  $V_{GS} = -5/15 \text{ V}$



**Reverse bias safe operating area (RBSOA), MOSFET**

$$I_D = f(V_{DS})$$

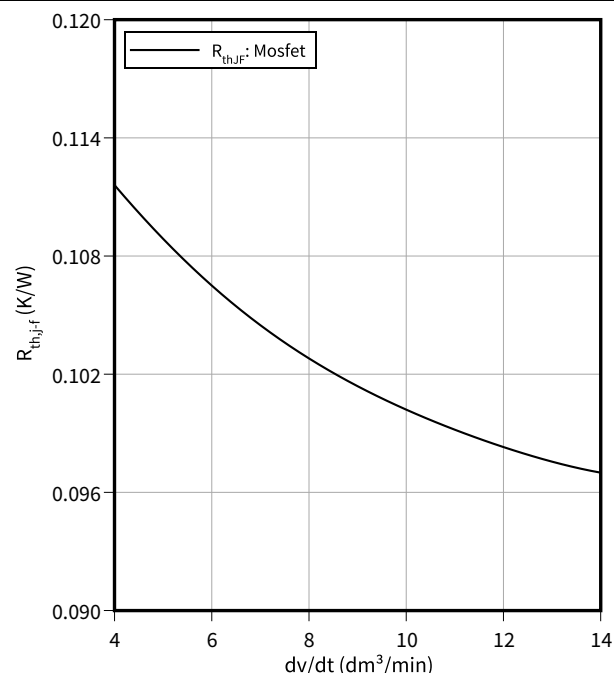
$R_{G,off} = 5.1 \Omega$ ,  $V_{GS} = +15/-5 \text{ V}$ ,  $T_{vj} = 150 \text{ °C}$



**Thermal impedance, MOSFET**

$$R_{th,j-f} = f(dv/dt)$$

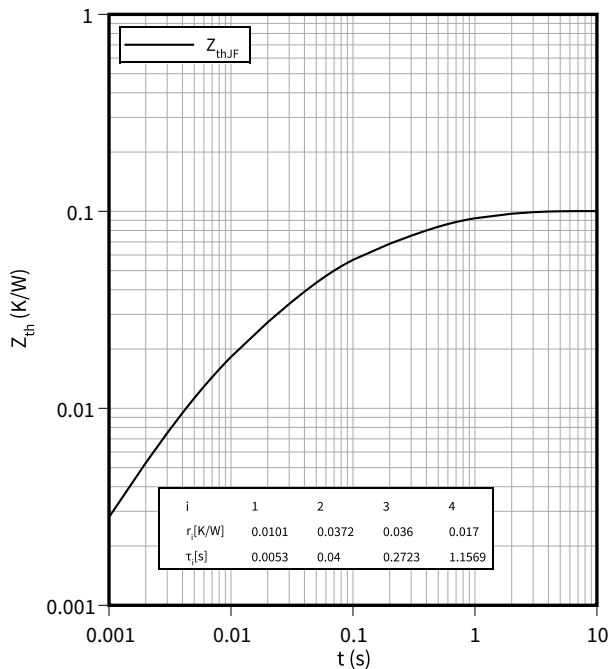
fluid = 50% water/50% ethylenglycol,  $T_f = 60 \text{ °C}$



5 Characteristics diagrams

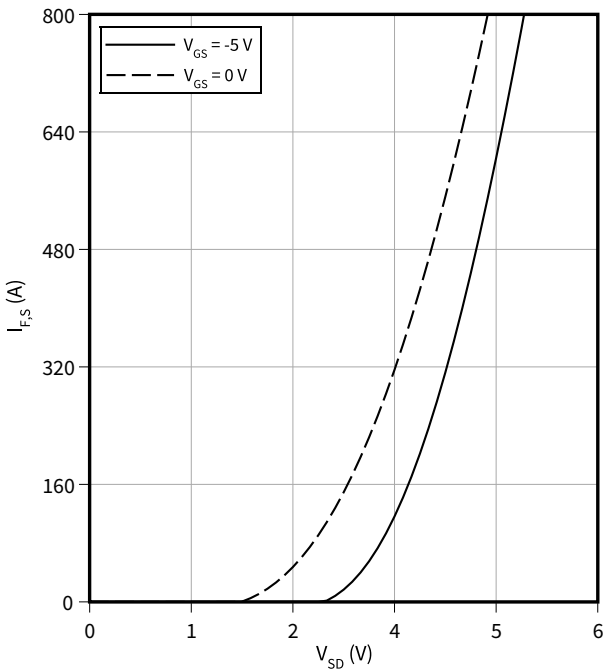
Transient thermal impedance , MOSFET

$Z_{th} = f(t)$   
 $\Delta V/\Delta t = 10 \text{ dm}^3/\text{min}$ , fluid = 50% water/50% ethylenglycol ,  $T_f = 60 \text{ }^\circ\text{C}$



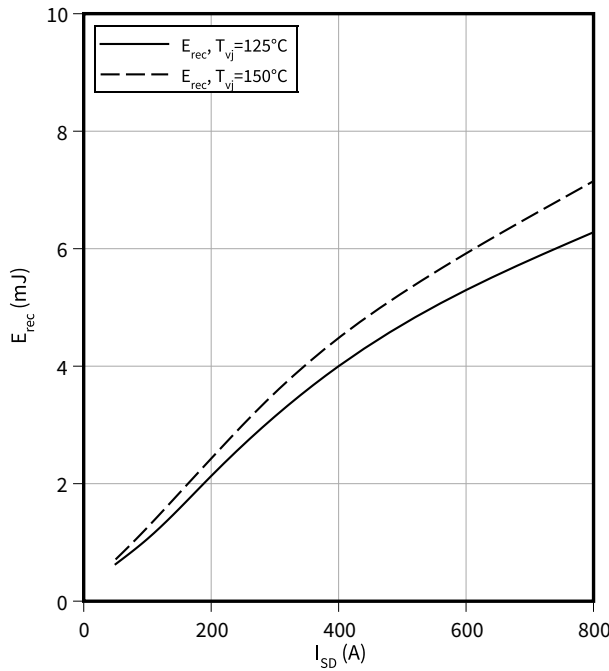
Forward characteristic body diode (typical), MOSFET

$I_{F,S} = f(V_{SD})$   
 $T_{vj} = 25 \text{ }^\circ\text{C}$



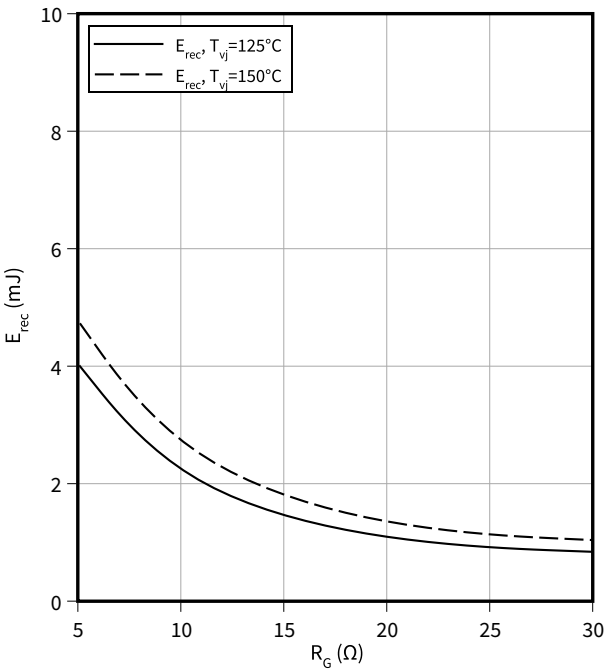
Switching losses body diode (typical), MOSFET

$E_{rec} = f(I_{SD})$   
 $V_r = 600 \text{ V}$ ,  $R_{G,on} = 5.1 \text{ } \Omega$ ,  $V_{GS} = -5/15 \text{ V}$



Switching losses body diode (typical), MOSFET

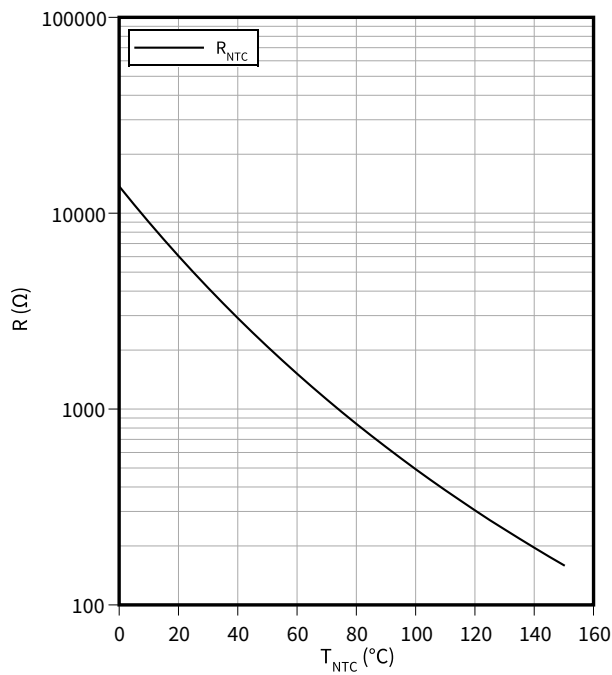
$E_{rec} = f(R_G)$   
 $V_r = 600 \text{ V}$ ,  $I_{F,S} = 400 \text{ A}$ ,  $V_{GS} = -5/15 \text{ V}$



5 Characteristics diagrams

Temperature characteristic (typical), NTC-Thermistor

$R = f(T_{NTC})$



6 Circuit diagram

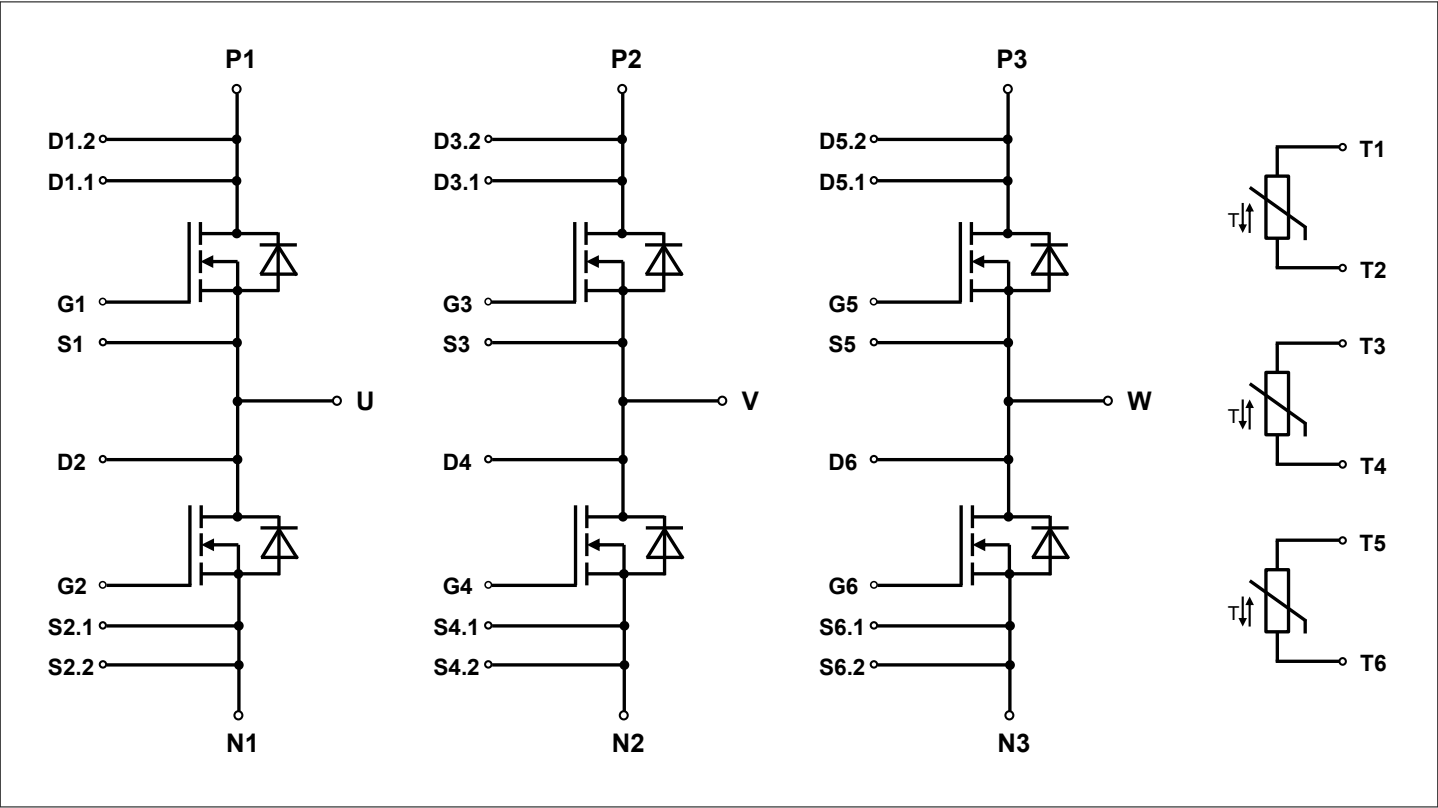


Figure 1

7 Package outlines

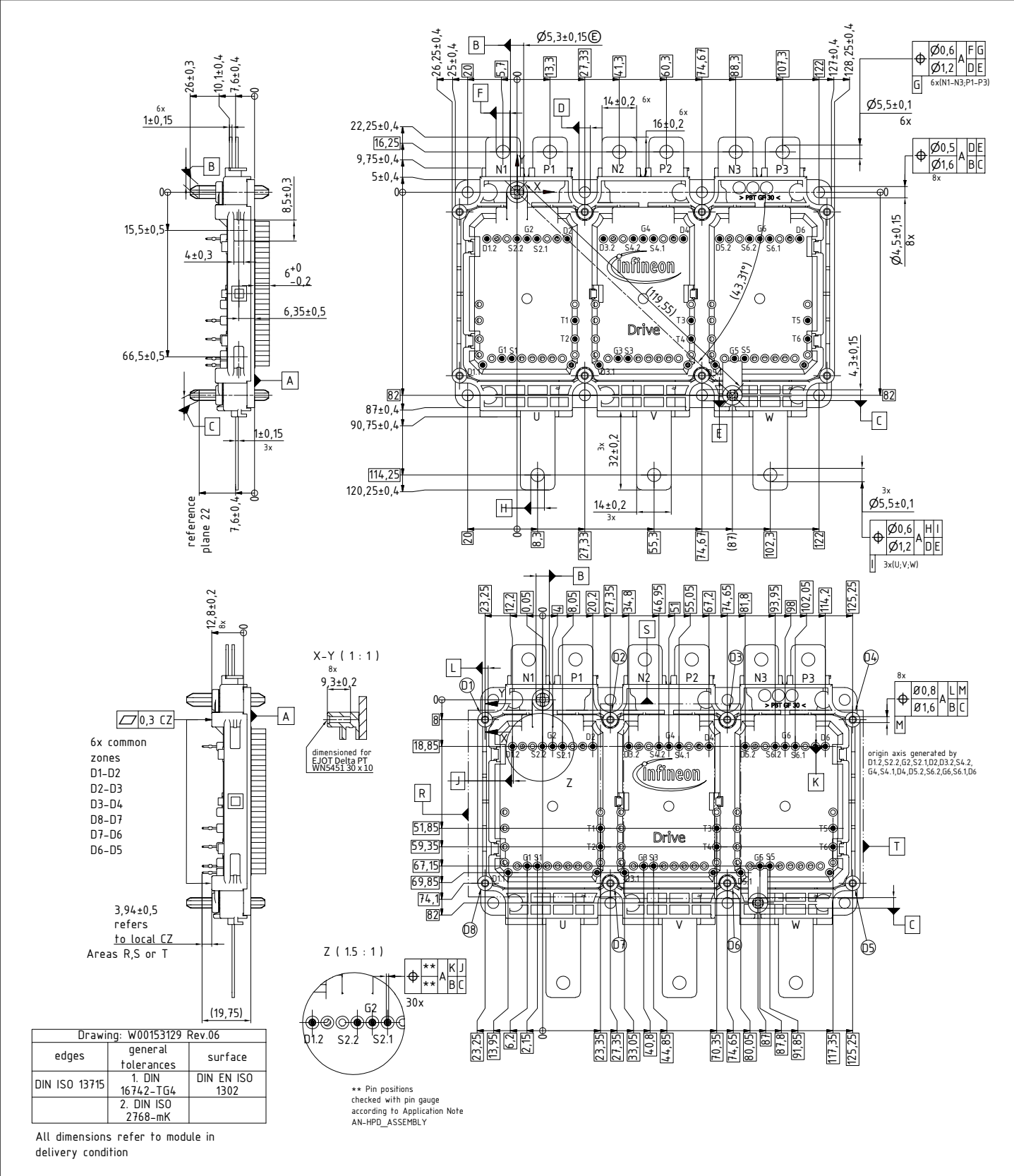


Figure 2

## 8 Module label code

| Module label code |                                                                                                                                                                                                                                            |                                                                  |                                                           |  |
|-------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------|-----------------------------------------------------------|--|
| Code format       | Data Matrix                                                                                                                                                                                                                                |                                                                  | Barcode Code128                                           |  |
| Encoding          | ASCII text                                                                                                                                                                                                                                 |                                                                  | Code Set A                                                |  |
| Symbol size       | 16x16                                                                                                                                                                                                                                      |                                                                  | 23 digits                                                 |  |
| Standard          | IEC24720 and IEC16022                                                                                                                                                                                                                      |                                                                  | IEC8859-1                                                 |  |
| Code content      | <i>Content</i><br>Module serial number<br>Module material number<br>Production order number<br>Date code (production year)<br>Date code (production week)                                                                                  | <i>Digit</i><br>1 – 5<br>6 - 11<br>12 - 19<br>20 – 21<br>22 – 23 | <i>Example</i><br>71549<br>142846<br>55054991<br>15<br>30 |  |
| Example           | <div></div> <div>7154914284655054991153071549142846550549911530</div> |                                                                  |                                                           |  |

| Packing label code |                                                                                                                                                           |                                              |                                                                   |                                                                |
|--------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------|-------------------------------------------------------------------|----------------------------------------------------------------|
| Code format        | Barcode Code128                                                                                                                                           |                                              |                                                                   |                                                                |
| Encoding           | Code Set A                                                                                                                                                |                                              |                                                                   |                                                                |
| Symbol size        | 34 digits                                                                                                                                                 |                                              |                                                                   |                                                                |
| Standard           | IEC8859-1                                                                                                                                                 |                                              |                                                                   |                                                                |
| Code content       | <i>Content</i><br>Module serial number<br>Module material number<br>Production order number<br>Date code (production year)<br>Date code (production week) | <i>Identifier</i><br>X<br>1T<br>S<br>9D<br>Q | <i>Digit</i><br>2 – 9<br>12 – 19<br>21 – 25<br>28 – 31<br>33 – 34 | <i>Example</i><br>95056609<br>2X0003E0<br>754389<br>1139<br>15 |
| Example            | <div></div> <div>X950566091T2X0003E0S754389D1139Q15</div>             |                                              |                                                                   |                                                                |

**Figure 3**

## Revision history

| Document revision | Date of release | Description of changes                                                                                                                              |
|-------------------|-----------------|-----------------------------------------------------------------------------------------------------------------------------------------------------|
| V1.0              | 2019-09-03      | Target datasheet                                                                                                                                    |
| V2.0              | 2021-01-26      | Preliminary datasheet                                                                                                                               |
| n/a               | 2020-10-05      | Datasheet migrated to a new system with a new layout and new revision number schema: target or preliminary datasheet = 0.xy; final datasheet = 1.xy |
| 1.00              | 2021-03-23      | Final datasheet                                                                                                                                     |
| 1.10              | 2022-07-19      | Adaption of product identification<br>Adding electrical feature diagram<br>Correction of typos                                                      |

## Trademarks

All referenced product or service names and trademarks are the property of their respective owners.

**Edition 2022-07-19**

**Published by**

**Infineon Technologies AG**  
**81726 Munich, Germany**

**© 2022 Infineon Technologies AG**  
**All Rights Reserved.**

**Do you have a question about any aspect of this document?**

**Email:** [erratum@infineon.com](mailto:erratum@infineon.com)

**Document reference**  
**IFX-AAD288-004**

## Important notice

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffheitsgarantie").

With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application.

## Warnings

Due to technical requirements products may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies office.

Except as otherwise explicitly approved by Infineon Technologies in a written document signed by authorized representatives of Infineon Technologies, Infineon Technologies' products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Infineon:](#)

[FS03MR12A6MA1LBBPSA1](#)